

VERTICAL DEFLECTION BOOSTER

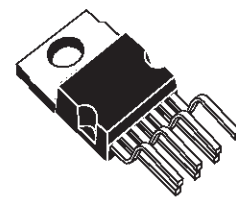
- POWER AMPLIFIER
- FLYBACK GENERATOR
- THERMAL PROTECTION
- OUTPUT CURRENT UP TO 2.0A_{PP}
- FLYBACK VOLTAGE UP TO 90V (on Pin 5)
- SUITABLE FOR DC COUPLING APPLICATION

DESCRIPTION

Designed for monitors and high performance TVs, the STV9379 vertical deflection booster delivers flyback voltages close to 90V.

The STV9379 operates with supplies up to 42V and provides up to 2A_{PP} output current to drive the yoke.

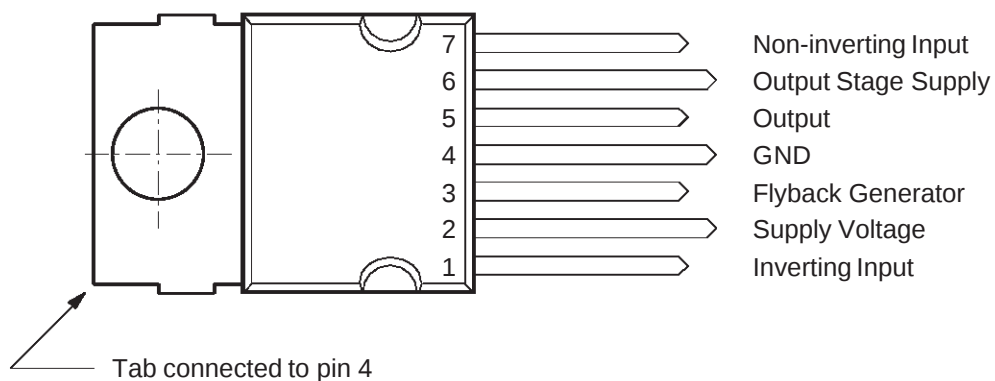
The STV9379 is offered in HEPTAWATT package.



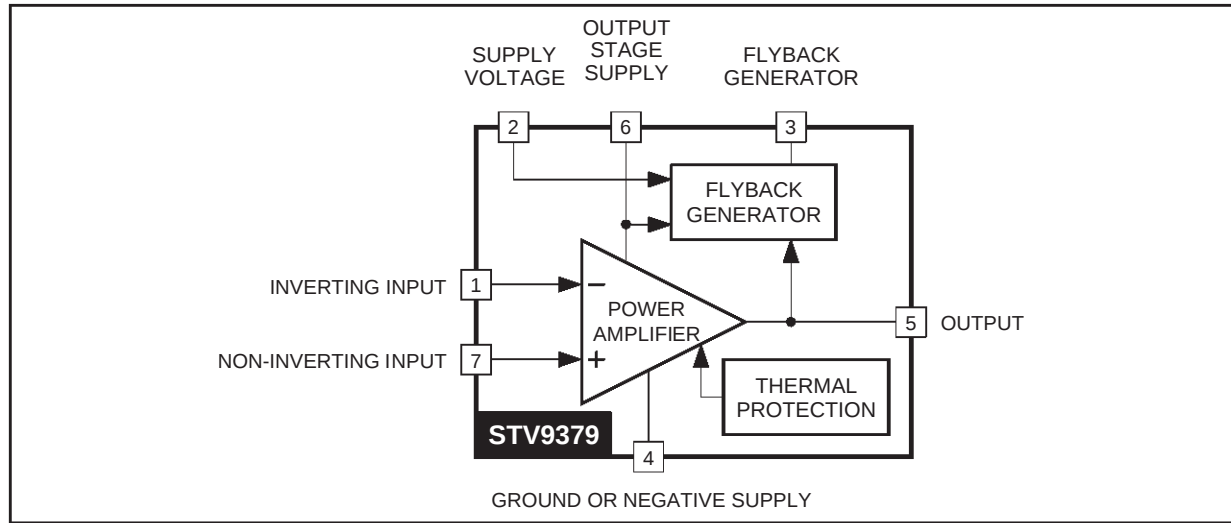
HEPTAWATT
(Plastic Package)

ORDER CODE : STV9379

PIN CONNECTIONS



BLOCK DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_S	Supply Voltage (Pin 2) (see note 1)	50	V
V_6	Flyback Peak Voltage (Pin 6) (see note 1)	100	V
V_1, V_7	Amplifier Input Voltage (Pins 1-7) (see note 1)	- 0.3, + V_S	V
I_O	Maximum Output Peak Current (see notes 2 and 3)	1.5	A
I_3	Maximum Sink Current (first part of flyback) ($t < 1\text{ms}$)	1.5	A
I_3	Maximum Source Current ($t < 1\text{ms}$)	1.5	A
V_{ESD}	ESD susceptibility : EIAJ Norm (200pF discharged through 0Ω)	300	V
T_{oper}	Operating Ambient Temperature	- 20, + 75	°C
T_{stg}	Storage Temperature	- 40, + 150	°C
T_j	Junction Temperature	+150	°C

9379-01.TBL

- Notes :**
1. Versus Pin 4.
 2. The output current can reach 4A peak for $t \leq 10\mu\text{s}$ (up to 120Hz).
 3. Provided SOAR is respected (see Figures 1 and 2).

THERMAL DATA

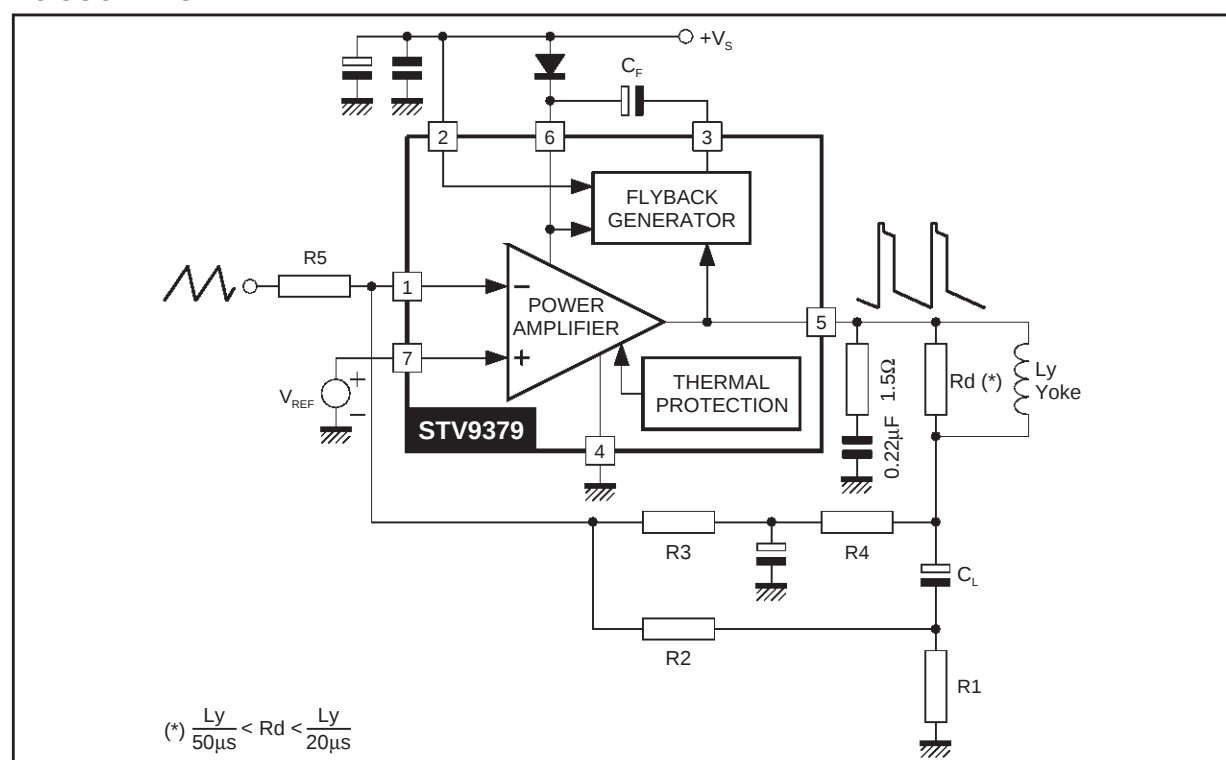
Symbol	Parameter	Value	Unit
$R_{th(j-c)}$	Junction-case Thermal Resistance Max.	3	°C/W
T_t	Temperature for Thermal Shutdown	150	°C
ΔT_t	Hysteresis on T_t	10	°C
T_{jr}	Recommended Max. Junction Temperature	120	°C

9379-02.TBL

ELECTRICAL CHARACTERISTICS(V_S = 42V, T_A = 25°C, unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
V _S	Operating Supply Voltage Range	Versus Pin 4	10		42	V
I ₂	Pin 2 Quiescent Current	I ₃ = 0, I ₅ = 0		10	20	mA
I ₆	Pin 6 Quiescent Current	I ₃ = 0, I ₅ = 0	5	10	30	mA
I _O	Max. Peak Output Current				1	A
I ₁	Amplifier Bias Current	V ₁ = 25V, V ₇ = 26V		- 0.15	- 1	μA
I ₇	Amplifier Bias Current	V ₁ = 26V, V ₇ = 25V		- 0.15	- 1	μA
V _{IO}	Offset Voltage				7	mV
ΔV _{IO} /dt	Offset Drift versus Temperature			- 10		μV/°C
GV	Voltage Gain		80			dB
V _{5L}	Output Saturation Voltage to GND (Pin 4)	I ₅ = 1A		1	1.5	V
V _{5H}	Output Saturation Voltage to Supply (Pin 6)	I ₅ = - 1A		1.6	2.1	V
V _{D5-6}	Diode Forward Voltage between Pins 5-6	I ₅ = 1A		1.5	2	V
V _{D3-2}	Diode Forward Voltage between Pins 3-2	I ₃ = 1A		1.5	2	V
V _{3L}	Saturation Voltage on Pin 3	I ₃ = 20mA		0.8	1.2	V
V _{3SH}	Saturation Voltage to Pin 2 (2nd part of flyback)	I ₃ = - 1A		2.1	2.9	V

9379-03.TBL

APPLICATION CIRCUITS**AC COUPLING**

9379-03.EPS

APPLICATION CIRCUITS (continued)
DC COUPLING

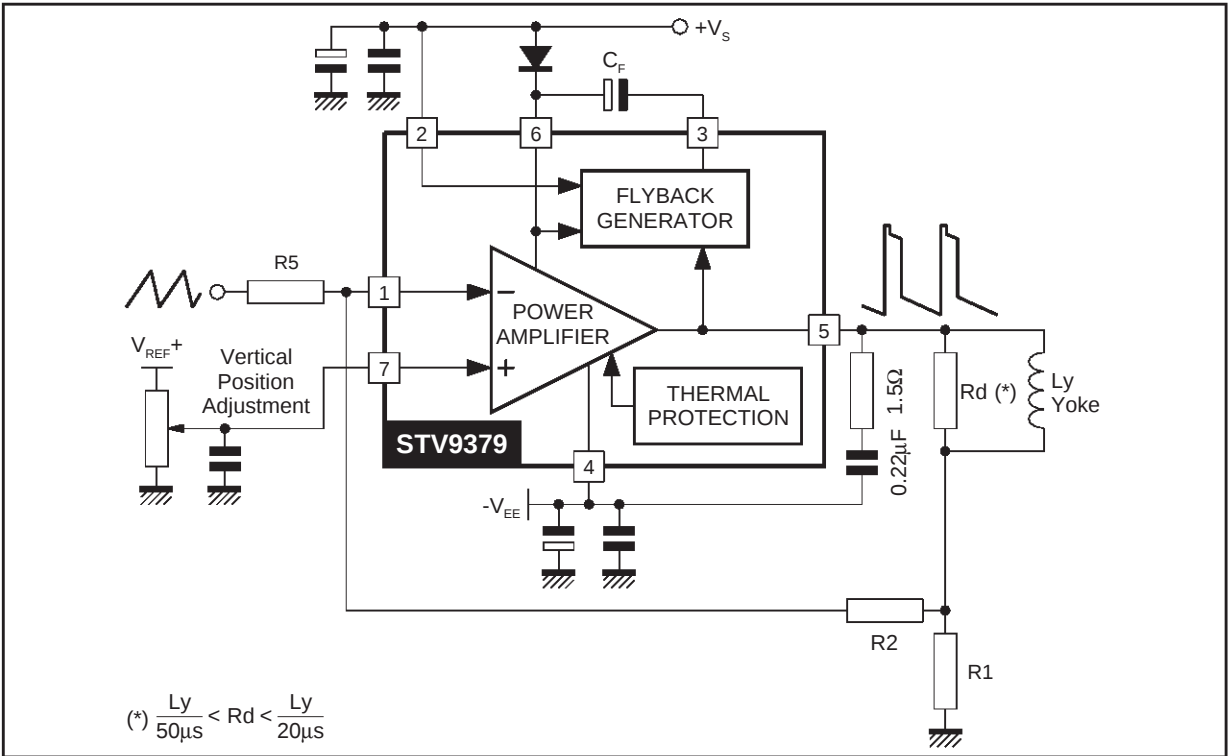
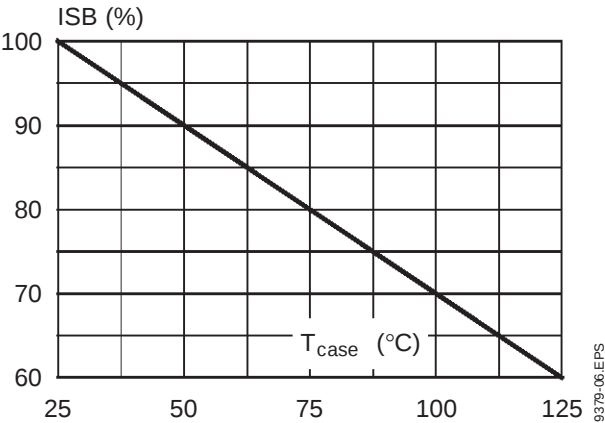
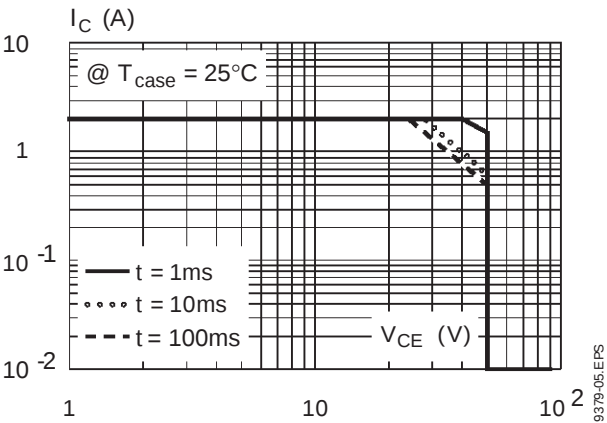
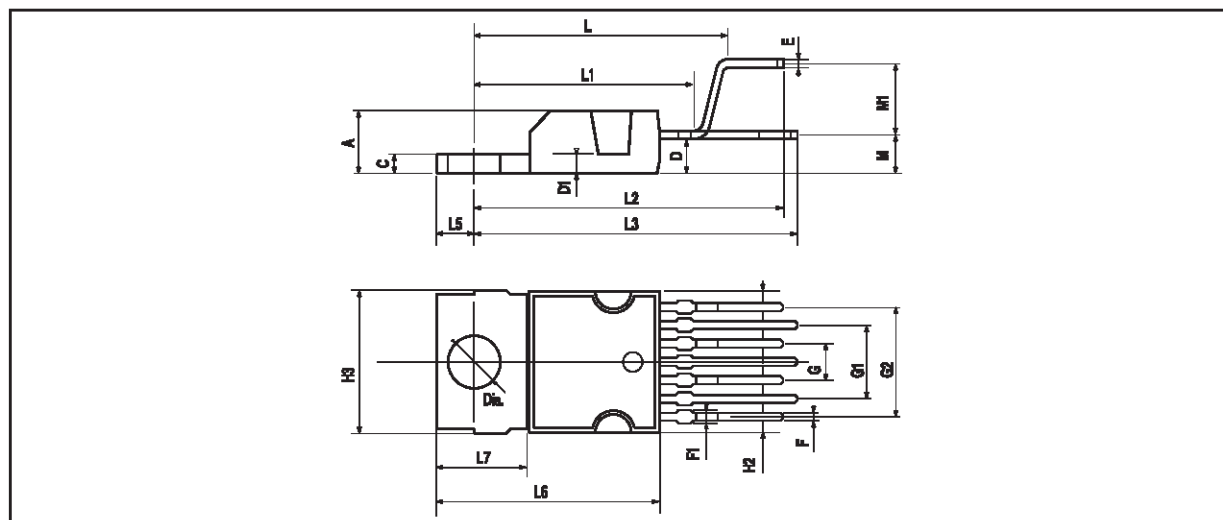


Figure 1 : Output Transistors SOA
(for secondary breakdown)

Figure 2 : Secondary Breakdown Temperature
Derating Curve
(ISB = secondary breakdown current)



PACKAGE MECHANICAL DATA : 7 PINS - PLASTIC HEPTAWATT



PM-HEPTV7ERS

Dimensions	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			4.8			0.189
C			1.37			0.054
D	2.4		2.8	0.094		0.110
D1	1.2		1.35	0.047		0.053
E	0.35		0.55	0.014		0.022
F	0.6		0.8	0.024		0.031
F1			0.9			0.035
G	2.41	2.54	2.67	0.095	0.100	0.105
G1	4.91	5.08	5.21	0.193	0.200	0.205
G2	7.49	7.62	7.8	0.295	0.300	0.307
H2			10.4			0.409
H3	10.05		10.4	0.396		0.409
L		16.97			0.668	
L1		14.92			0.587	
L2		21.54			0.848	
L3		22.62			0.891	
L5	2.6		3	0.102		0.118
L6	15.1		15.8	0.594		0.622
L7	6		6.6	0.236		0.260
M		2.8			0.110	
M1		5.08			0.200	
Dia.	3.65		3.85	0.144		0.152

HEPTV.TBL

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